Declaration and Power of Attorney For Patent Application

特許出願宣言書及び委任状



Japanese Language Declaration 日本語宣言書

下記の氏名の発明者として、私は以下の通り宣言します。	As a below named inventor, I hereby declare that:
私の住所、私書箱、国籍は下記の私の氏名の後に記載された通りです。	My residence, post office address and citizenship are as stated next to my name.
下記の名称の発明に関して請求範囲に記載され、特許出願している発明内容について、私が最初かつ唯一の発明者(下記の氏名が一つの場合)もしくは最初かつ共同発明者であると(下記の名称が複数の場合)信じています。	I believe I am the original, first and sole inventor (if only one name is listed below) or an original, first and joint inventor (if plural names are listed below) of the subject matter which is claimed and for which a patent is sought on the invention entitled SEMICONDUCTOR DEVICE HAVING SEMICONDUCTOR CIRCUIT COMPRISING SEMICONDUCTOR ELEMENT, AND METHOD FOR MANUFACTURING SAME
上記発明の明細書(下記の欄で×印がついていない場合は、本書に添付)は、	The specification of which is attached hereto unless the following box is checked:
□月日に提出され、米国出願番号または特許協定条約国際出願番号をとし、	as United States Application Number or

私は、特許請求範囲を含む上記訂正後の明細書を検討し、 内容を理解していることをここに表明します。 I hereby state that I have reviewed and understand the contents of the above identified specification, including the claims, as amended by any amendment referred to above.

and was amended on (if applicable).

PCT International Application Number

09/362,192

私は、連邦規則法典第37編第1条56項に定義されるとおり、特許資格の有無について重要な情報を開示する義務があることを認めます。

I acknowledge the duty to disclose information which is material to patentability as defined in Title 37, Code of Federal Regulations, Section 1.56.

Japanese Language Declaration

(日本語宣言書)

私は、米国法典第 35 編 119 条(a)-(d)項又は 365 条(b)項 I hereby claim foreign priority under Title 35, United に基き下記の、米国以外の国の少なくとも一カ国を指定して いる特許協力条約 365(a)項に基く国際出願、又は外国での 特許出願もしくは発明者証の出願についての外国優先権を ここに主張するとともに、優先権を主張している、本出願の前 に出願された特許または発明者証の外国出願を以下に、枠 内をマークすることで、示しています。

States Code, Section 119(a)-(d) or 365(b) of any foreign application(s) for patent or inventor's certificate, or 365(a) of any PCT International application which designated at least one country other than the United States, listed below and have also identified below, by checking the box any foreign application for patent or inventor's is

	•	certificate, or PCT International date before that of the applic claimed.	
Prior Foreign Application(s) 外国での先行出願			Priority Not Claime 優先権主張ない
10-221986	<u>Japan</u>	August 5, 1998	
(Number) (番号)	(Country) (国名)	(Day/Month/Year Filed) (出願年月日)	
(Number) (番号)	(Country) (国名)	(Day/Month/Year Filed) (出願年月日)	
(Number) (番号)	(Country) (国名)	(Day/Month/Year Filed) (出願年月日)	
私は、第 35 編米国法典 119 条(6 特許出願規定に記載された権利をこ		I hereby claim the benefit under Code, Section 119(e) of any application(s) listed below.	
(Application No.) (出願番号)	(Filing Date) (出題日)	(Application No.) (出願番号)	(Filing Date) (出願日)
私は、下記の米国法典第 35 編 1 国特許出願に記載された権利、又応許協力条約 365 条(c)に基く権利を本出願の各請求範囲の内容が米国が項又は特許協力条約で規定された大出願に開示されていない限り、その対略で本出願書の日本国内または特別での期間中に入手された、連邦規制で定義された特許資格の有無に関す明示義務があることを認識しています。	は米国を指定している特 ここに主張します。また、 去典代35編112条第1 7法で先行する米国特許 先行米国出願提出日以 5協力条約国際提出日ま 法典第37編1条56項 つる重要な情報について	I hereby claim the benefit under Code, Section 120 of any United 365(c) of any PCT International the United States, listed below a matter of each of the claims of disclosed in the prior United States application in the manner provide of Title 35, United States acknowledge the duty to disclosed material to patentability as defining the provided of the patentability as defining the patentability as defining data and the national or PCT International or PCT International control of the patentability and the national or PCT International control of the patentability and the patentability and the national or PCT International control of the patentability and the patentability an	d States application(s), or all application designating and, insofar as the subject of this application is not ates or PCT International led by the first paragraph Code Section 112, I use information which is ned in Title 37, Code of 1.56 which became of the prior application
(Application No.) (出願番号)	(Filing Date) (出願日)	 (Status: Patented, Pendi (現況: 特許許可済、組	

(Application No.)	(Filing Date)	(Status: Patented, Pending, Abandoned)
(出願番号)	(出願日)	(現识:特許許可済、継続中、放棄済)
(Application No.)	(Filing Date)	(Status: Patented, Pending, Abandoned)
(出頭番号)	(出類日)	(現況: 特許許可済、継続中、放棄済)
(Application No.)	(Filing Date)	(Status: Patented, Pending, Abandoned)
(出願番号)	(出類日)	(現況:特許許可済、継続中、放棄済)
(Application No.)	(Filing Date)	(Status: Patented, Pending, Abandoned)
(出額番号)	(出題日)	(現况:特許許可済、継続中、放棄済)
(Application No.)	(Filing Date)	(Status: Patented, Pending, Abandoned)
(出願番号)	(出願日)	(現況:特許許可済、継続中、放棄済)
(Application No.)	(Filing Date)	(Status: Patented, Pending, Abandoned)
(出願番号)	(出願日)	(現況: 特許許可済、継続中、放棄済)
(Application No.)	(Filing Date)	(Status: Patented, Pending, Abandoned)
(出願番号)	(出願日)	(現況: 特許許可済、継続中、放棄済)

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I hereby declare that all statements made herein of my own knowledge are true and that all statements made on information and belief are believed to be true; and further that these statements were made with the knowledge that willful false statements and the like so made are punishable by fine or imprisonment, or both, under Section 1001 of Title 18 of the United States Code and that such willful false statements may jeopardize the validity of the application or any patent issued thereon.

Japanese Language Declaration

(日本語宣言書)

委任状: 私は下記の発明者として、本出願に関する一切の手続きを 米特許商標局に対して遂行する弁護士または代理人として、下記の 者を帯名いたします。(弁護士、または代理人の氏名及び登録番号 を明記のこと) POWER OF ATTORNEY: As a named inventor, I hereby appoint the following attomey(s) and/or agent(s) to prosecute this application and transact all business in the Patent and Trademark Office connected therewith (list name and registration number).

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The undersigned hereby authorizes any U. S. attorney or agent named herein to accept and follow instructions from as to any action to be taken in the Patent and Trademark Office regarding this application without direct communication between the U. S. attorney or agent and the undersigned. In the event of a change in the persons from whom instructions may be taken, the U. S. attorneys or agents named herein will be so notified by the undersigned.

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